imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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2SB1121

Bipolar Transistor -25V, -2A, Low VCE(sat) PNP Single PCP



Applications

• Voltage regulators, relay drivers, lamp drivers, electrical equipment

Features

- Adoption of FBET, MBIT processes
- Large current capacity and wide SOA
- Low collector to emitter saturation voltage • Fast switching speed
- Ultrasmall size making it easy to provide high-density, small-sized hybrid IC's

Specifications

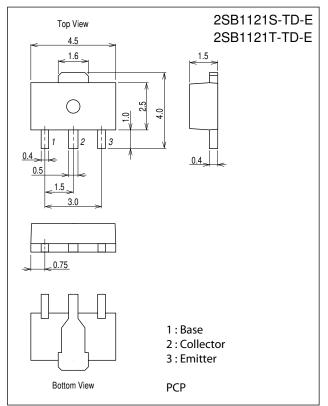
Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector to Base Voltage	V _{CBO}		-30	V
Collector to Emitter Voltage	VCEO		-25	V
Emitter to Base Voltage	VEBO		-6	V
Collector Current	IC		-2	Α
Collector Current (Pulse)	ICP		-5	А

Continued on next page.

Package Dimensions

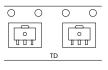
unit : mm (typ) 7007B-004



Product & Package Information

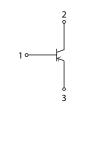
- Package
- : PCP : SC-62, SOT-89, TO-243
- JEITA, JEDEC • Minimum Packing Quantity : 1,000 pcs./reel

Packing Type: TD





Electrical Connection



Marking



Continued from preceding page.

Parameter	Symbol	Conditions	Ratings	Unit
Collector Dissipation	PC		500	mW
		When mounted on ceramic substrate (250mm ² ×0.8mm)	1.3	W
Junction Temperature	Тј		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

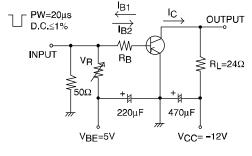
Electrical Characteristics at $Ta = 25^{\circ}C$

Parameter	Symbol			Ratings		
		Conditions	min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =-20V, I _E =0A			-0.1	μA
Emitter Cutoff Current	IEBO	V _{EB} =-4V, I _C =0A			-0.1	μA
DC Current Gain	hFE1	V _{CE} =-2V, I _C =-100mA	140*		400*	
	h _{FE} 2	V _{CE} =-2V, I _C =-1.5A	65			
Gain-Bandwidth Product	fT	V _{CE} =-10V, I _C =-50mA		150		MHz
Output Capacitance	Cob	V _{CB} =-10V, f=1MHz		32		pF
Collector to Emitter Saturation Voltage	V _{CE} (sat)	I _C =-1.5A, I _B =-75mA		-0.35	-0.6	V
Base to Emitter Saturation Voltage	V _{BE} (sat)	I _C =-1.5A, I _B =-75mA		-0.85	-1.2	V
Collector to Base Breakdown Voltage	V _(BR) CBO	I _C =-10μΑ, I _E =0Α	-30			V
Collector to Emitter Breakdown Voltage	V(BR)CEO	I _C =-1mA, R _{BE} =∞	-25			V
Emitter to Base Breakdown Voltage	V(BR)EBO	I _E =-10μA, I _C =0A	-6			V
Turn-ON Time	ton			60		ns
Storage Time	t _{stg}	See specified Test Circuit		350		ns
Fall Time	tf	1		25		ns

*: The 2SB1121 is classified by 100mA hFE as follows:

Rank	S	Т
h _{FE}	140 to 280	200 to 400

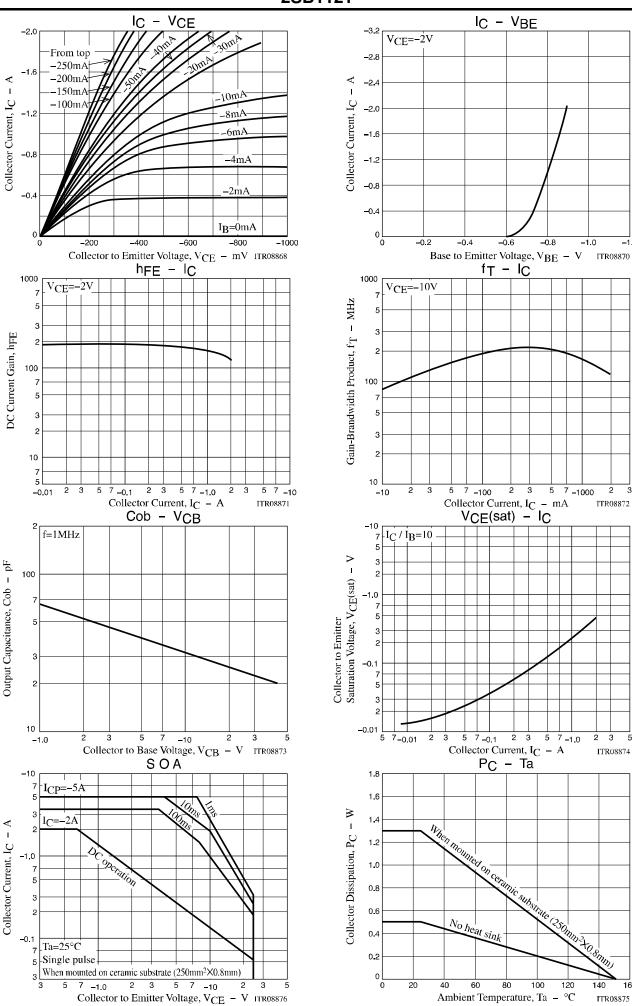
Switching Time Test Circuit



 $I_{C}=20I_{B1}=-20I_{B2}=-0.5A$

Ordering Information

Device	Package	Shipping	Memo
2SB1121S-TD-E 2SB1121T-TD-E	PCP	1,000pcs./reel	Pb-Free



160

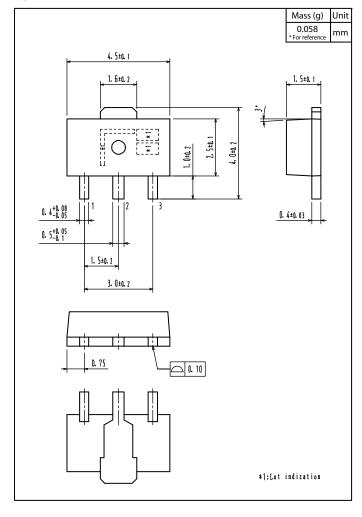
-1.2

3

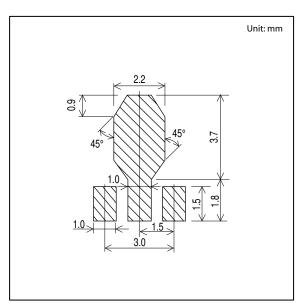
5

Outline Drawing

2SB1121S-TD-E 2SB1121T-TD-E



Land Pattern Example



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